

## Claims

1. (original) An article of manufacture comprising:

a machine-readable medium having a plurality of machine readable instructions, wherein when the instructions are executed by a processor, the instructions provide to manage a system for:

dividing a flash memory block into individual data areas or sectors, wherein each sector has an associated header for identifying a sector's status; and

rearranging a plurality of Power Loss Recovery (PLR) status bits such that all the PLR status bits are extracted from a header and data area and coalesced into a predetermined region.

2. (original) The article of manufacture of claim 1 wherein the system is a flash media.

3. (original) The article of manufacture of claim 2 wherein the flash media comprises a flash memory to support error correcting code (ECC).

4. (original) The article of manufacture of claim 3 wherein the flash memory supports multilevel states.

5. (original) The article of manufacture of claim 1 wherein the predetermined region does not have ECC protection and relies on level 1 and level 4 states.

6.(currently amended) A method for organizing PLR status bits comprising;

storing a plurality of PLR status bits in a predetermined region within a flash memory;

and

selecting a multi-level state for the plurality of PLR status bits, wherein selecting one of a plurality of multi-state levels comprises selecting either a level 1 or level 4 states for the plurality of PLR status bits.

7. (cancelled) The method of claim 6 further comprises ECC protection for the flash memory except for the PLR status bits.

8. (cancelled) The method of claim 6 wherein selecting one of a plurality of multi-state levels comprises selecting either a level 1 or level 4 states for the plurality of PLR status bits.

9. (cancelled) The method of claim 6 wherein the flash memory is incorporated within a flash media system.

10. (currently amended) A method for organizing PLR status bits comprising;

storing a plurality of PLR status bits in a predetermined region within a flash memory;  
selecting a multi-level state for the plurality of PLR status bits, wherein selecting one of a plurality of multi-state levels comprises selecting either a level 1 or level 4 states for the plurality of PLR status bits; and

protecting the flash memory with ECC except for the PLR status bits.

11. (cancelled) The method of claim 10 wherein selecting one of a plurality of multi-state levels comprises selecting either a level 1 or level 4 states for the plurality of PLR status bits.
12. (cancelled) The method of claim 10 wherein the flash memory is incorporated within a flash media system.
13. (currently amended) An article of manufacture comprising:
- a machine-readable medium having a plurality of machine readable instructions, wherein when the instructions are executed by a processor, the instructions provide to manage a system for:
    - rearranging a plurality of Power Loss Recovery (PLR) status bits such that all the PLR status bits are extracted from a header and data area and coalesced into a predetermined region;
    - selecting a multi-level state for the plurality of PLR status bits; and
    - protecting ~~a the~~ flash memory with ECC except for the PLR status bits.
14. (original) The article of manufacture of claim 13 wherein the system is a flash media.
15. (original) The article of manufacture of claim 14 wherein the flash media comprises a flash memory to support error correcting code (ECC).
16. (original) The article of manufacture of claim 13 wherein the predetermined region does not have ECC protection and relies on level 1 and level 4 states.

17. (currently amended) A flash memory to support ECC comprising:
- a flash memory block divided into individual data areas and sectors, wherein each sector has an associated header for identifying a sector's status; and
  - a plurality of Power Loss Recovery (PLR) status bits such that all the PLR status bits are extracted from a header and data area and coalesced into a predetermined region;
  - the ECC to detect and correct errors for ~~a the~~ flash memory block except for the PLR status bits.
18. (original)The apparatus of claim 17 wherein the flash memory supports multi-level states.
19. (original)The apparatus of claim 18 wherein PLR status bits are Level 1 or Level 4 states.
20. (currently amended) A system comprising:
- a first logic to request data from a flash memory, wherein the flash memory comprises:
    - individual data areas and sectors, wherein each sector has an associated header for identifying a sector's status;
    - a plurality of Power Loss Recovery (PLR) status bits such that all the PLR status bits are extracted from a header and data area and coalesced into a predetermined region; and
    - the ECC to detect and correct errors for ~~a~~ [the] flash memory block except for the PLR status bits.
21. (original) The system of claim 20 further comprising a wireless interface.

22. (original) The system of claim 20 wherein the flash memory supports multi-level states.

23. (original) The system of claim 20 wherein PLR status bits are Level 1 or Level 4 states.

24. (original) The system of claim 20 wherein the first logic is a microprocessor.

25. (original) The system of claim 20 further comprising a second logic to request data from the flash memory, the second logic is a digital signal processor.